L Number	Hits	Search Text	DB	Time stamp
1	6169	jfet$1 or (junction-fet$1) or (junction adj fet$1) or (junction adj field adj effect)	USPAT; US-PGPUB; JPO	2004/09/29 08:57
2	150893	mosfet$1 or mos or (metal adj oxide adj semiconduct$3)	USPAT; US-PGPUB; JPO	2004/09/29 08:57
3	161693	gate$1 and source$1 and drain$1	USPAT; US-PGPUB; JPO	2004/09/29 08:58
4	1125351	silicon or semiconduct$3	USPAT; US-PGPUB; JPO	2004/09/29 08:58
5	3517	(jfet$1 or (junction-fet$1) or (junction adj fet$1) or (junction adj field adj effect)) and (gate$1 and source$1 and drain$1) and (silicon or semiconduct$3)	USPAT; US-PGPUB; JPO	2004/09/29 08:58
6	28534	vertical near3 (channel$1 or transistor$1)	USPAT; US-PGPUB; JPO	2004/09/29 08:59
7	538	((jfet$1 or (junction-fet$1) or (junction adj fet$1) or (junction adj field adj effect)) and (gate$1 and source$1 and drain$1) and (silicon or semiconduct$3)) and (vertical near3 (channel$1 or transistor$1))	USPAT; US-PGPUB; JPO	2004/09/29 08:59
8	438	(((jfet$1 or (junction-fet$1) or (junction adj fet$1) or (junction adj field adj effect)) and (gate$1 and source$1 and drain$1) and (silicon or semiconduct$3)) and (vertical near3 (channel$1 or transistor$1))) and (mosfet$1 or mos or (metal adj oxide adj semiconduct$3))	USPAT; US-PGPUB; JPO	2004/09/29 08:59
9	360468	etch$3	USPAT; US-PGPUB; JPO	2004/09/29 08:59
10	332381	438/$.ccls. or 257/$.ccls.	USPAT; US-PGPUB; JPO	2004/09/29 09:00
11	318	((((jfet$1 or (junction-fet$1) or (junction adj fet$1) or (junction adj field adj effect)) and (gate$1 and source$1 and drain$1) and (silicon or semiconduct$3)) and (vertical near3 (channel$1 or transistor$1))) and (mosfet$1 or mos or (metal adj oxide adj semiconduct$3))) and (438/$.ccls. or 257/$.ccls.) and etch$3	USPAT; US-PGPUB; JPO	2004/09/29 09:00

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